AP6120/8120

Microelectronic Materials & Processing

Professor Paul K. Chu

Course Objectives



 Reduces performance-robbing system bottlenecks

Boosts performance for many applications, especially memory intensive applications

 PC3200, PC2700, PC2100 or PC1600 DDR SDRAM support:

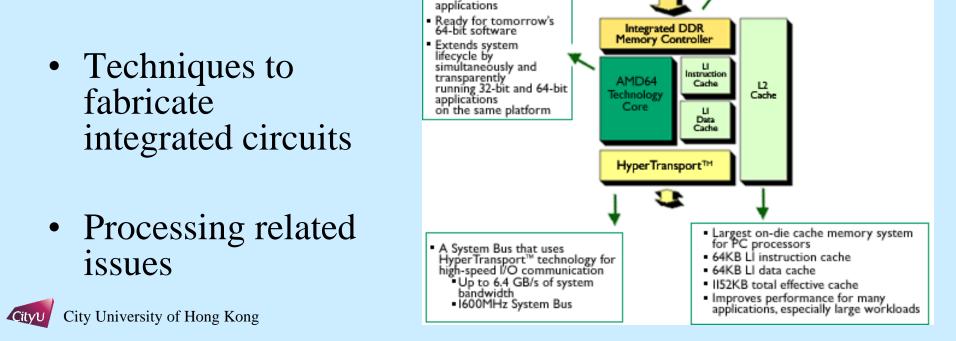
Up to 3.2 GB/s memory

Unbuffered DIMMs
64-bit interface

bandwidth

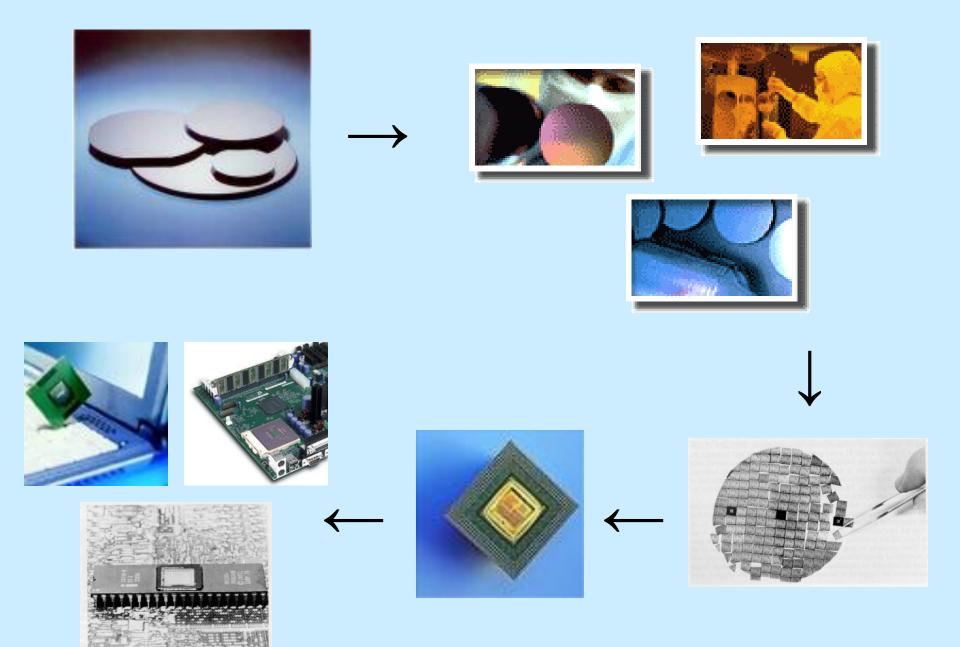
AMD Athlon[™] 64 Processor Architecture

 Simple microelectronic devices and building blocks of integrated circuits



Leading-edge

performance for today's 32-bit



Recommended Textbooks

- Semiconductor Devices: Physics and Technology (2nd Edition), S. M. Sze, *Wiley*, 2002
- VLSI Technology (2nd Edition), S. M. Sze (Editor), McGraw Hill, 1988
- Solid State Electronic Device (5th Edition), B. G. Streetman and S. Banerjee, *Prentice Hall*, 2000
- ULSI Technology, C. Y. Chang & S. M. Sze (Editors), *McGraw Hill*, 1996

Covered Topics (1)

- (1) Semiconductor Materials & Physics
- (2) Crystal Growth and Wafer Preparation
- (3) Epitaxy
- (4) Oxidation
- (5) Lithography
- (6) Etching

Website - http://www6.cityu.edu.hk/appkchu/AP6120/Notes.htm



Covered Topics (2)

- (7) Thin Film Deposition
- (8) Diffusion
- (9) Ion Implantation and Annealing
- (10) Metallization
- (11) Testing, Assembly, and Packaging

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Grading Methodology

• Continuous Assessment (40%)

Homework

Mid-Term Examination

Mini-Project

• Final Examination (60%)